NCE Automotive N-Channel Super Trench II Power MOSFET

Description

The NCEAP25N10AK uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

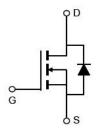
General Features

- $$\begin{split} \bullet \ V_{DS} = &100 V, I_D = &37 A \\ R_{DS(ON)} = &21 m\Omega \ (typical) \ @ \ V_{GS} = &10 V \\ R_{DS(ON)} = &26 m\Omega \ (typical) \ @ \ V_{GS} = &4.5 V \end{split}$$
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔVds tested
- AEC-Q101 qualified

TO-252-2L



Top View



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP25N10AK	NCEAP25N10AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	37	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	26.8	А
Pulsed Drain Current	I _{DM}	148	А
Maximum Power Dissipation	P _D	70	W
Derating factor		0.47	W/°C
Single pulse avalanche energy (Note 1)	E _{AS}	97	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	$^{\circ}\!\mathbb{C}$



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NCEAP25N10AK

Thermal Characteristic

Thermal Resistance, Junction-to-Case	R _{eJC}	2.14	°C/W
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Electrical Characteristics (T_C=25°Cunless otherwise noted)

Symbol	Condition	Min	Тур	Max	Unit
		'			
BV _{DSS}	V _{GS} =0V I _D =250µA	100	-	-	V
I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA
I _{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA
		•	,		
V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.1	1.7	2.5	V
	V _{GS} =10V, I _D =20A	-	21	25	mΩ
RDS(ON)	V _{GS} =4.5V, I _D =20A	-	26	30	mΩ
g FS	V _{DS} =5V,I _D =20A	-	19	-	S
		•			
Clss	V _{DS} =50V,V _{GS} =0V,	-	1317.6	-	PF
Coss		-	123.9	-	PF
Crss	F-1.UIVITIZ	-	19.3	-	PF
		•			
t _{d(on)}		-	13	-	nS
t _r	V_{DD} =50V, I_{D} =20A V_{GS} =10V, R_{G} =3 Ω	-	15	-	nS
t _{d(off)}		-	22	-	nS
t _f		-	6	-	nS
Qg	V _{DS} =50V,I _D =20A,	-	27.6	-	nC
Q _{gs}		-	5.5	-	nC
Q _{gd}	V _{GS} =10V	-	6.9	-	nC
			-	,	
V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Is		-	-	37	Α
t _{rr}	T _J = 25°C, I _F = 20A	-	40	-	nS
Qrr	di/dt = 100A/µs	-	85	-	nC
	BVDSS IDSS IGSS IGSS VGS(th) RDS(ON) -	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	BV _{DSS}	BV _{DSS}	BV _{DSS}

Notes:

- 1. EAS condition : Tj=25 $^{\circ}\text{C}\text{,V}_{DD}\text{=}50\text{V}\text{,V}_{G}\text{=}10\text{V}\text{,L=}0.5\text{mH}\text{,Rg=}25\Omega$
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T_{J(MAX)}=175°C. The SOA curve provides a single pulse rating.





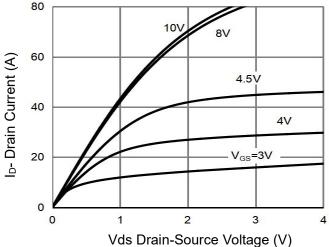


Figure 1 Output Characteristics

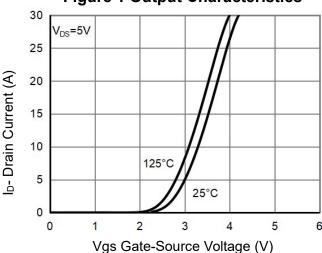


Figure 2 Transfer Characteristics

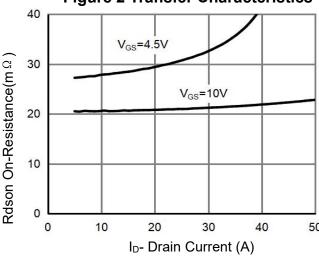


Figure 3 Rdson- Drain Current

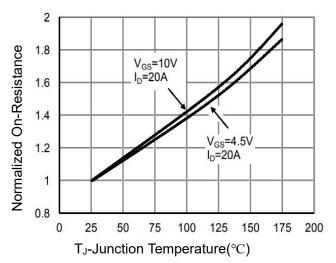
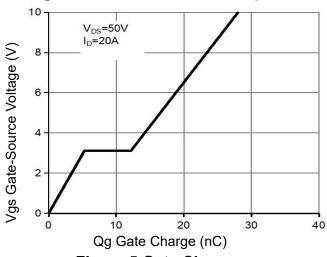


Figure 4 Rdson-Junction Temperature



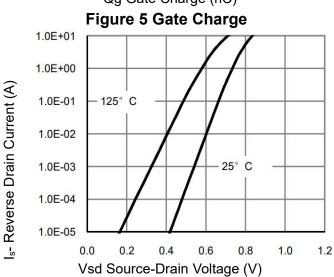


Figure 6 Source- Drain Diode Forward



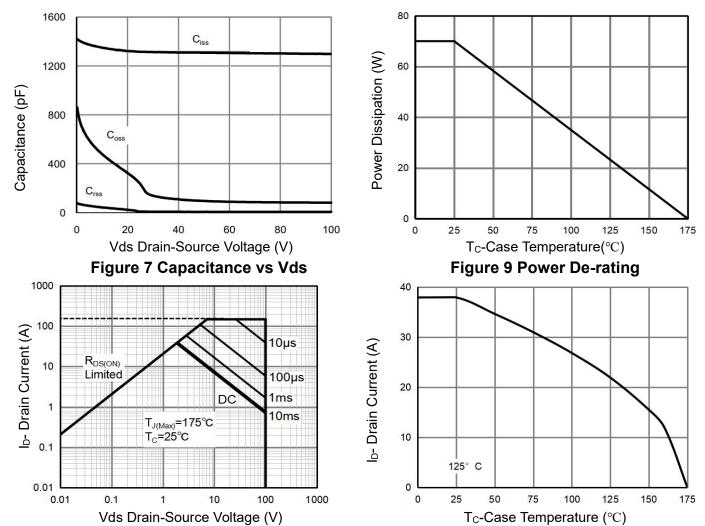
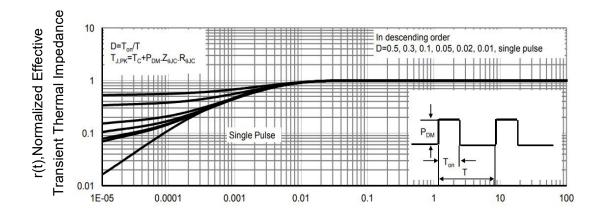


Figure 8 Safe Operation Area (Note3)

Figure 10 Current De-rating

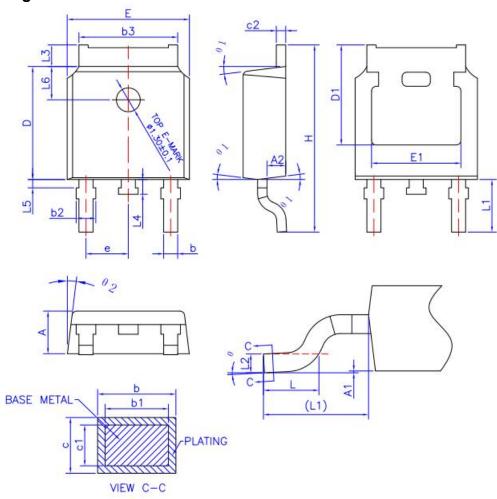


Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252-2L Package Information





COMMON DIMENSIONS (UNITS OF MEASURE =MILLIMETER)

SYMBOL	MIN	NOM	MAX	
Α	2.20	2.30	2.38	
A1	0		0.10	
A2	0.90	1.01	1.10	
b	0.72		0.85	
b1	0.71	0.76	0.81	
b2	0.72		0.90	
b3	5.13	5.33	5.46	
С	0.47		0.60	
c1	0.46	0.51	0.56	
c2	0.47		0.60	
D	6.00	6.10	6.20	
D1	5.25			
E	6.50	6.60	6.70	
E1	4.70	444		
е	2.186	2.286	2.386	
Н	9.80	10.10	10.40	
L	1.40	1.50	1.70	
L1	2.90 REF			
L2	0.508 BSC			
L3	0.90	20/200	1.25	
L4	0.60	0.80	1.00	
L5	0.15	0.75		
L6	1.80 REF			
θ	0°	8°		
θ1	5°	7°	9°	
θ2	5°	7°	9°	



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